

ECE145a / 218a Bilateral Tuned Amplifier Design

Mark Rodwell

University of California, Santa Barbara

rodwell@ece.ucsb.edu 805-893-3244, 805-893-3262 fax

Stability

Unconditionally stable if $\|\Gamma_{in}\| < 1$ for all possible Γ_L .

Equivalently : unconditionally stable if $\|\Gamma_{out}\| < 1$ for all possible Γ_S .

A 2-port is unconditionally stable if the Rollet stability factor $K > 1$, where

$$1) K = \frac{1 - \|S_{11}\|^2 - \|S_{22}\|^2 + \|S_{11}S_{22} - S_{12}S_{21}\|^2}{2 \cdot \|S_{12}S_{21}\|}$$

and

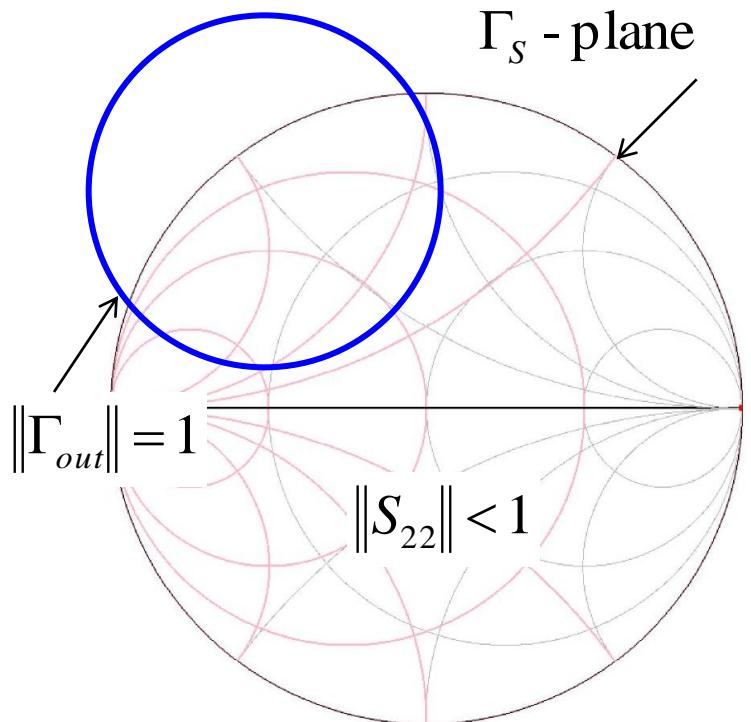
$$2a) \|S_{11}S_{22} - S_{12}S_{21}\| < 1.$$

An alternative 2nd condition is that the stability measure B_1 be positive, where

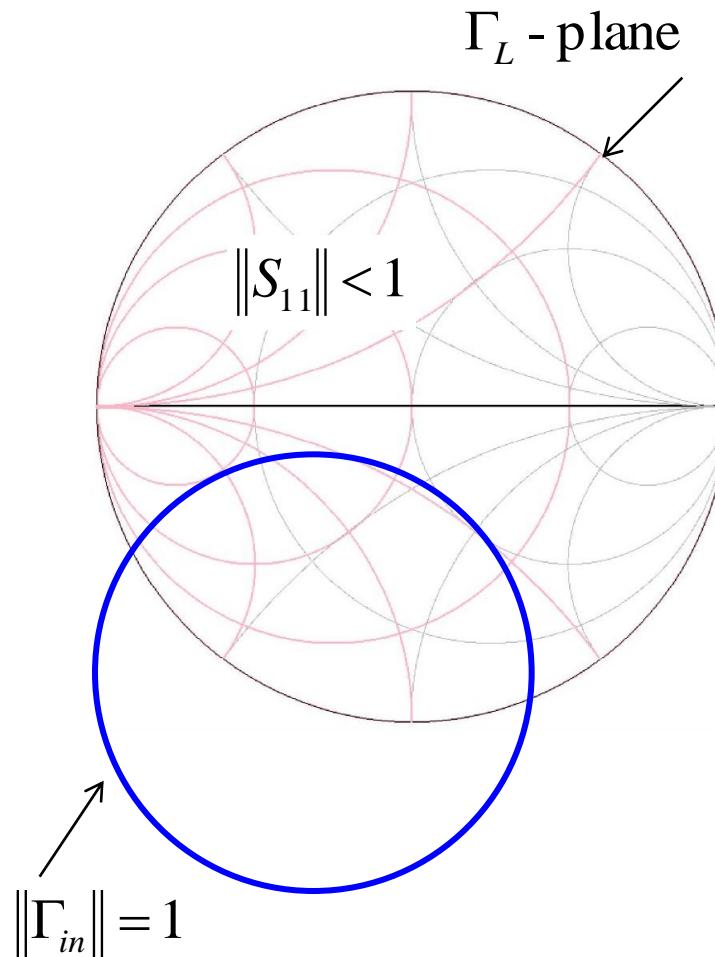
$$2b) B_1 = 1 + \|S_{11}\|^2 - \|S_{22}\|^2 + \|S_{11}S_{22} - S_{12}S_{21}\|^2$$

Potentially Unstable Amplifier

Source stability circle

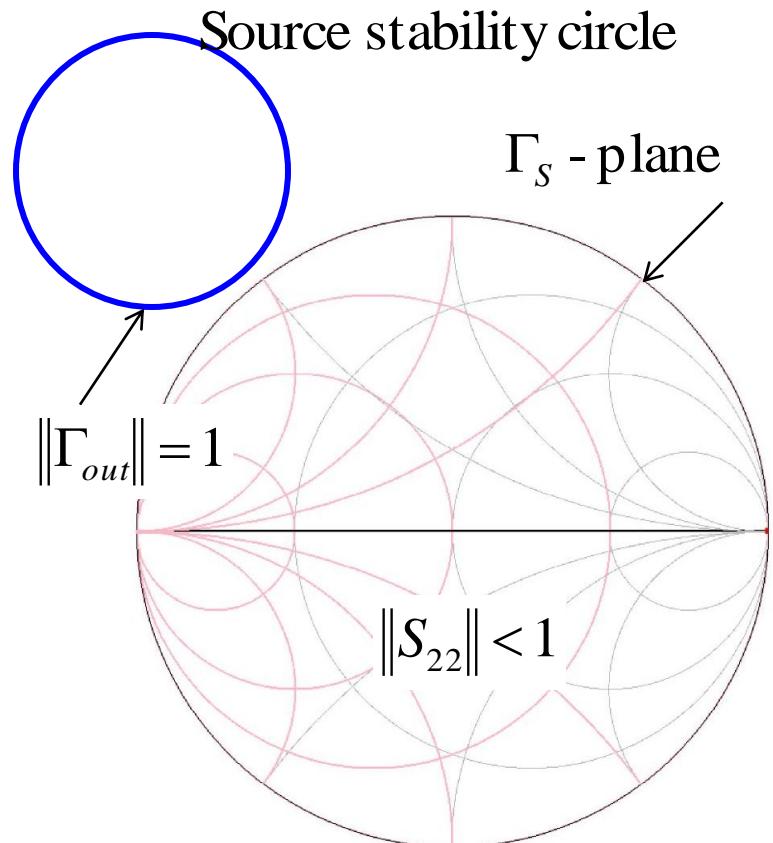


Load stability circle

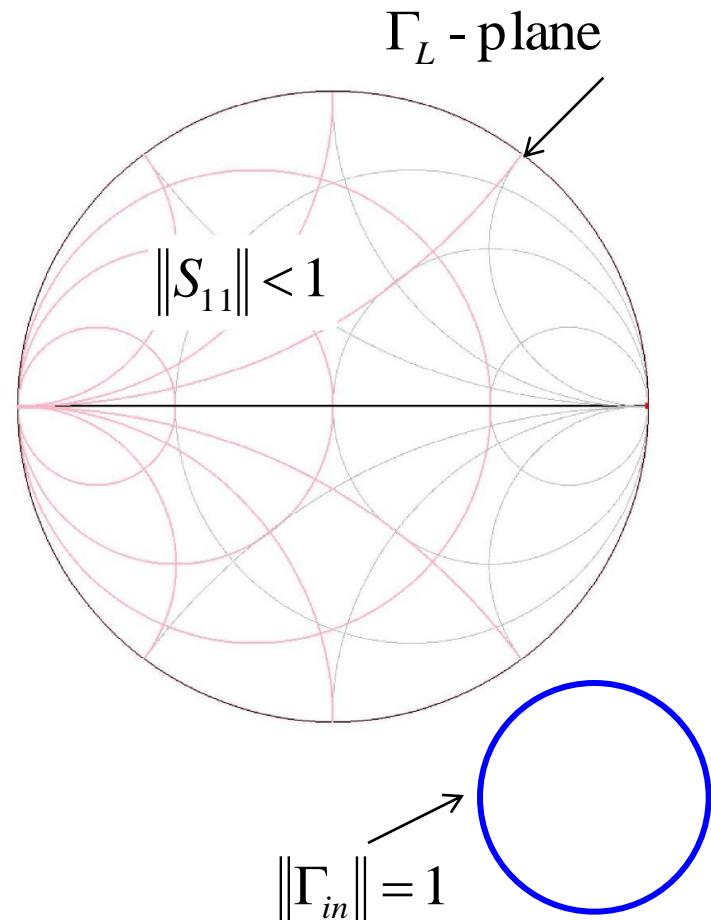


This is a test at one specific frequency; must test at all frequencies.

Unconditionally stable Amplifier

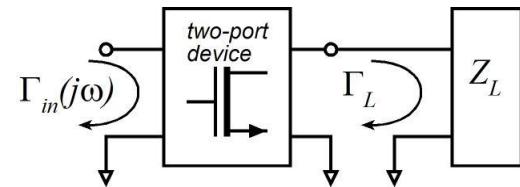
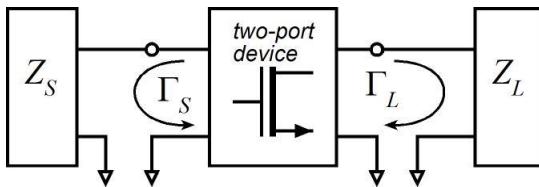


Load stability circle



This is a test at one specific frequency; must test at all frequencies.

Why Might MAG Not Exist ?



If the network is potentially unstable,
then by placing Γ_L within the load stability circle,
we force $\|\Gamma_{out}\| > 1$.

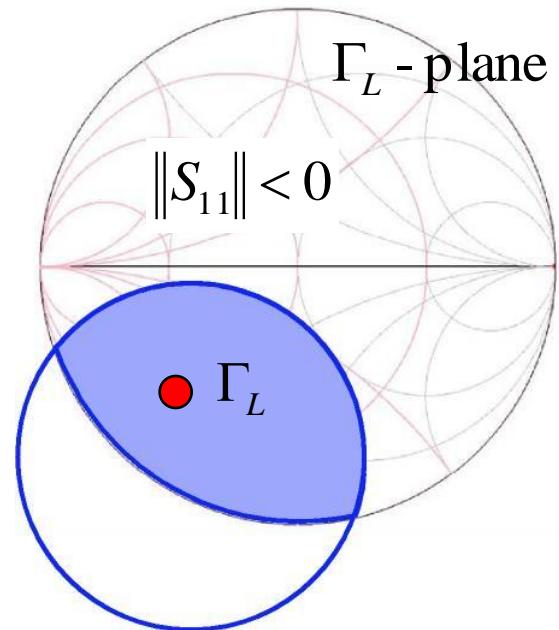
The device then has negative input resistance.

Appropriate choice of source impedance
will then cause oscillation.

If we adjust Γ_S and Γ_L to obtain
the highest possible gain,
we will instead obtain infinite gain (oscillation).

The maximum available gain is infinite. This is *not* good.

Load stability circle



Computing Maximum Available Gain

$$G_{\max} = \frac{P_{AVA}}{P_{in}} \xrightarrow{\text{iff } P_{AVA}=P_{load} \text{ and } P_{in}=P_{AVG}} \frac{P_{load}}{P_{AVG}} = G_T$$

we now need $\Gamma_L = \Gamma_{out}^*$ and $\Gamma_s = \Gamma_{in}^*$

we must simultaneously solve

$$\Gamma_{in} = S_{11} + \Gamma_L \frac{S_{21}S_{12}}{1 - S_{22}\Gamma_L} = \Gamma_s^* \text{ and } \Gamma_{out} = S_{22} + \Gamma_s \frac{S_{21}S_{12}}{1 - S_{11}\Gamma_s} = \Gamma_L^*$$

and then substitute into

$$G_T = \frac{1 - \|\Gamma_s\|^2}{\|1 - \Gamma_{in}\Gamma_s\|^2} \cdot \|S_{21}\|^2 \cdot \frac{1 - \|\Gamma_L\|^2}{\|1 - S_{22}\Gamma_L\|^2}$$

The calculations are long, and will not be shown.

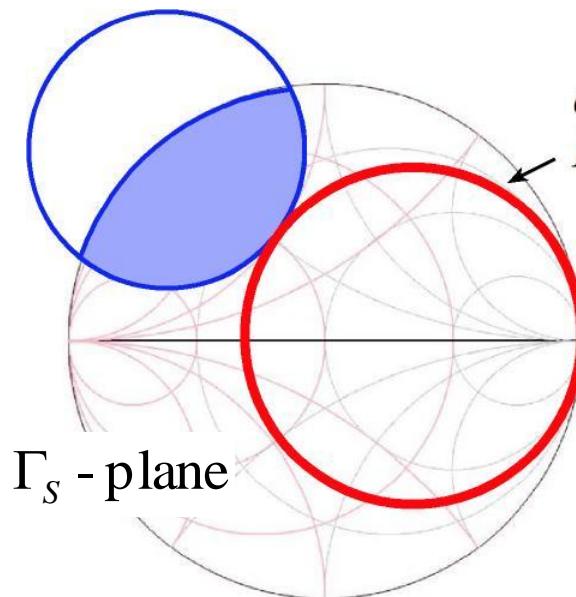
Maximum Available Gain

$$G_{\max} = \left\| \frac{S_{21}}{S_{12}} \right\| \cdot \left(K - \sqrt{K^2 - 1} \right)$$

where $K = \frac{1 - \|S_{11}\|^2 - \|S_{22}\|^2 + \|S_{11}S_{22} - S_{12}S_{21}\|^2}{2 \cdot \|S_{12}S_{21}\|}$ (Rolle stability factor).

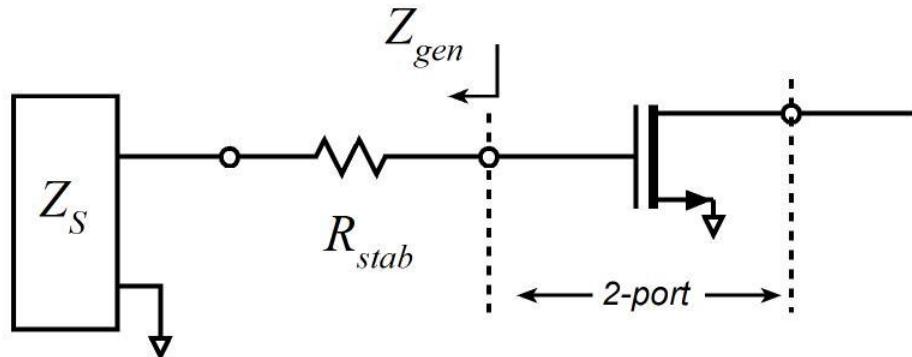
Note that G_{\max} is only defined for an unconditionally stable network,
i.e. $K > 1$ and $B_1 > 0$.

Stabilization: if device is potentially unstable



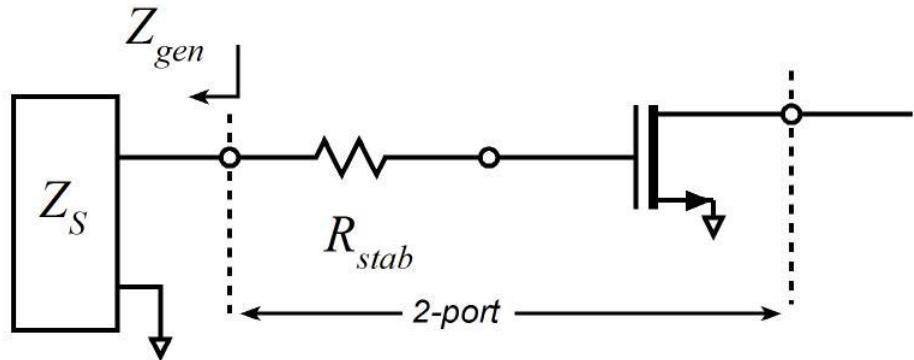
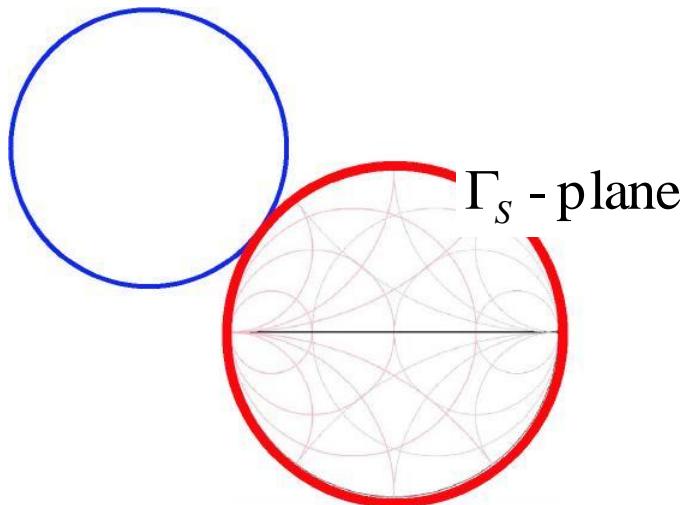
*circle for
 $R=R_{stab}$*

Γ_s - plane



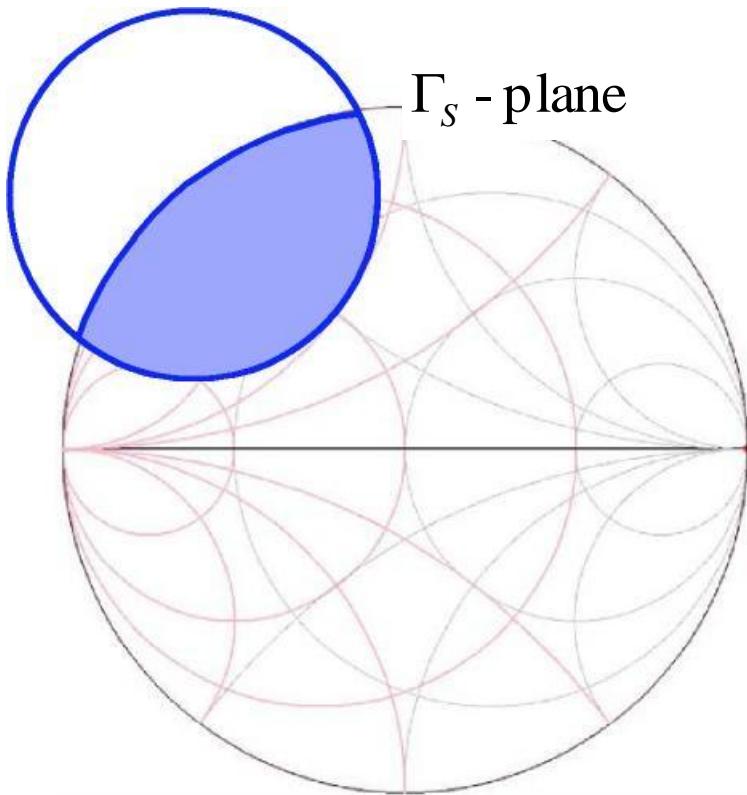
Adding series resistance R_{stab} as shown constraints Z_{gen} to lie within stable region.

Stabilization: if device is potentially unstable

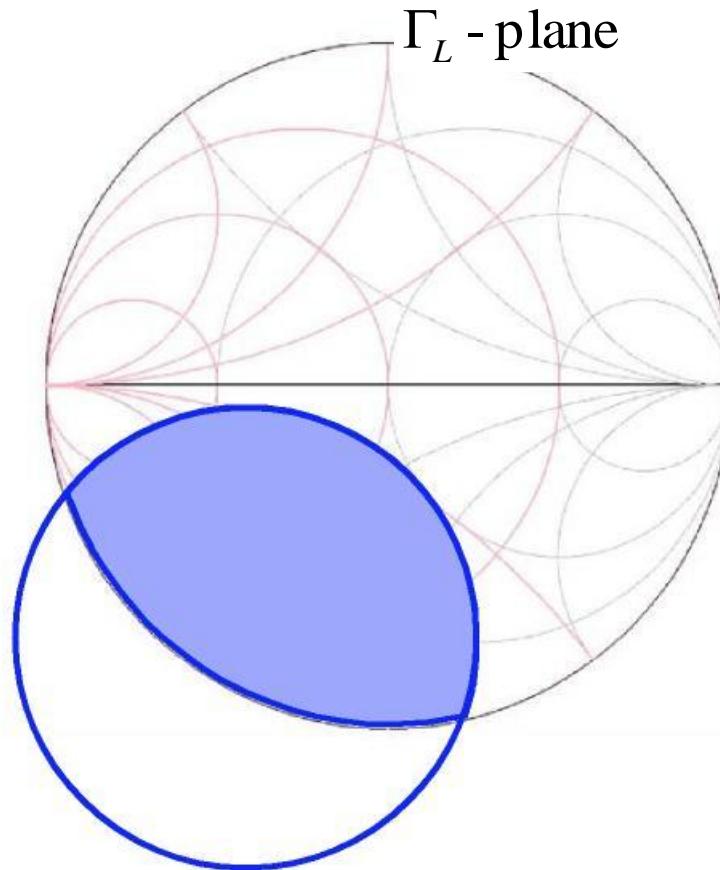


If we include R_{stab} in the 2 - port being simulated in the CAD software, the stability cirle moves outwards as shown..

4 Obvious Stabilization Methods



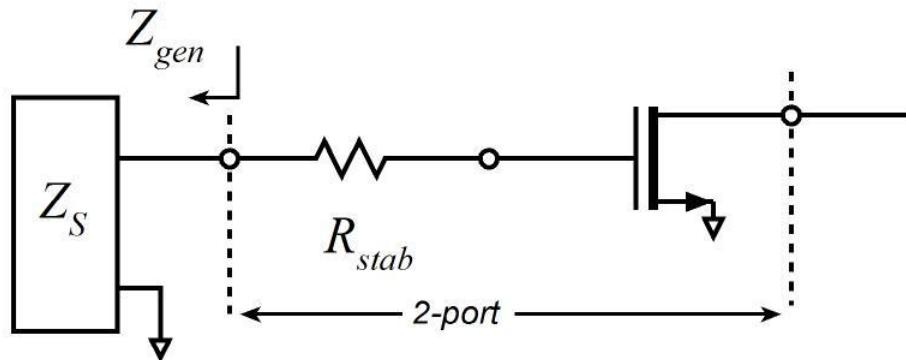
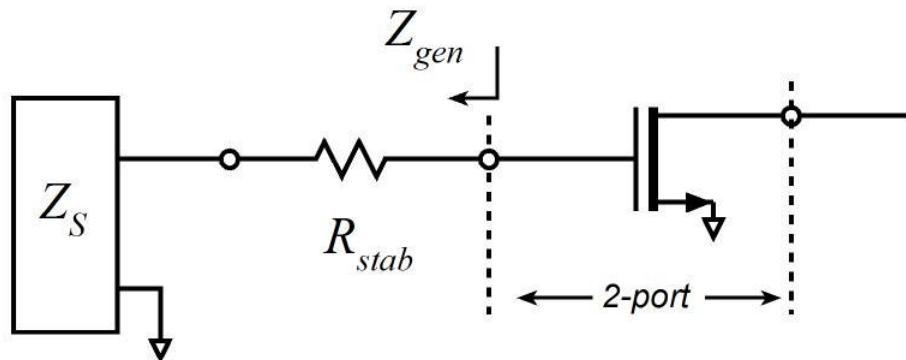
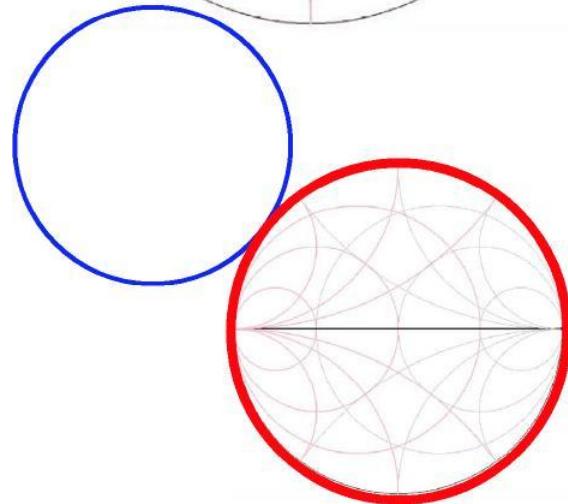
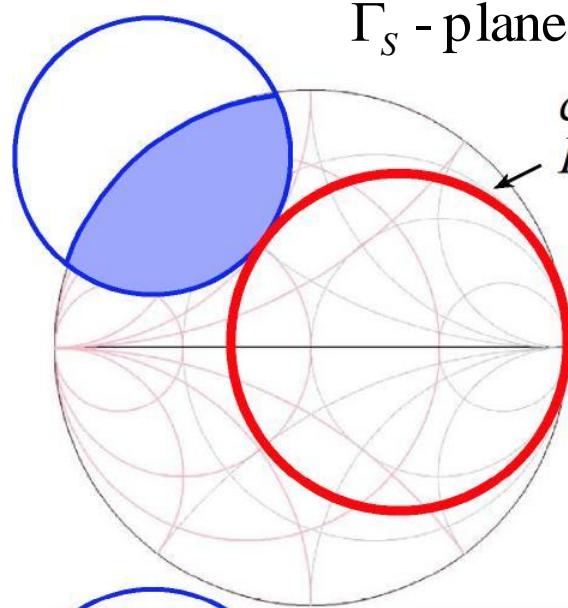
Γ_s - plane



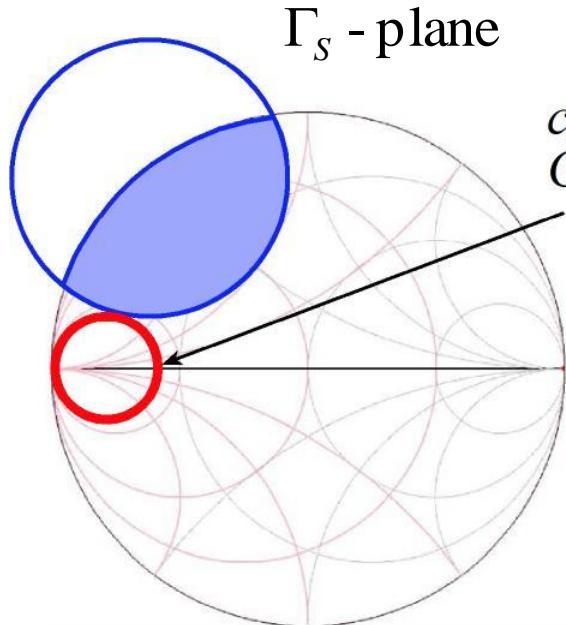
Γ_L - plane

Given these stability circles, four stabilization methods are immediately apparent.

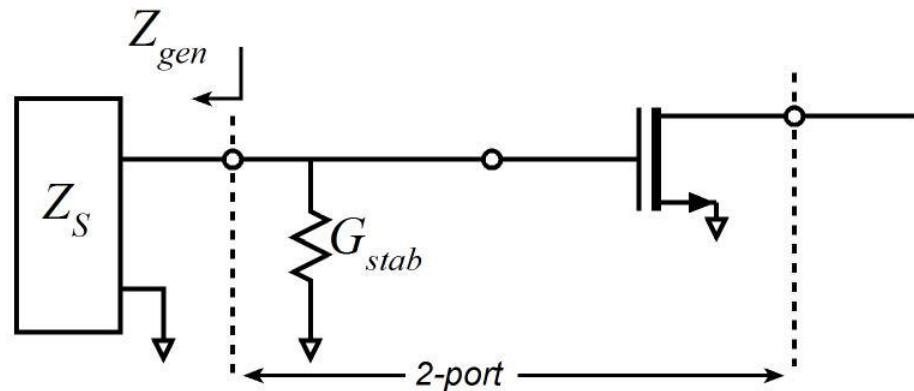
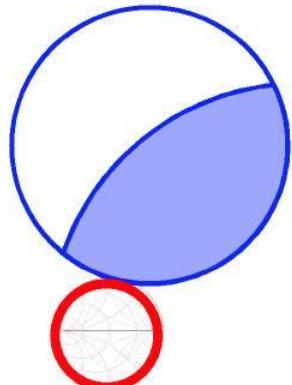
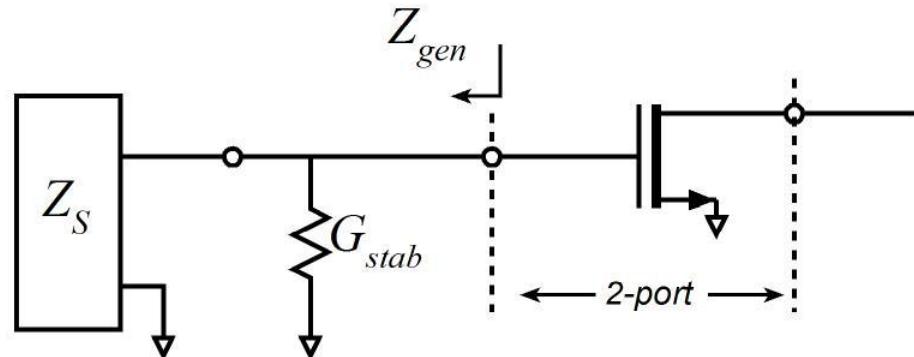
Series Stabilization On Input



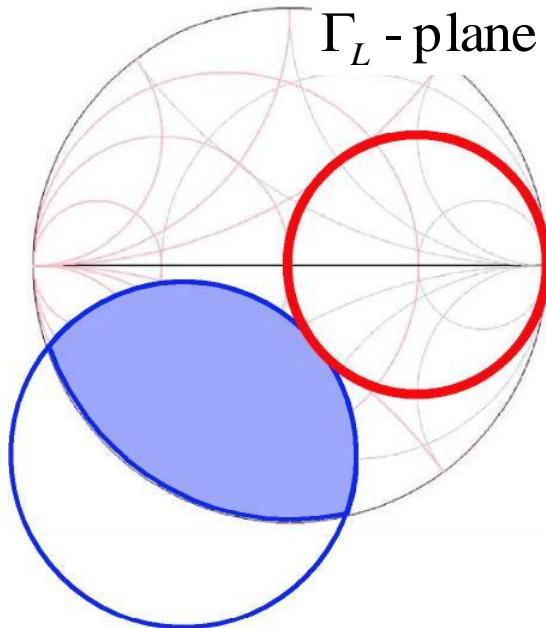
Shunt Stabilization On Input



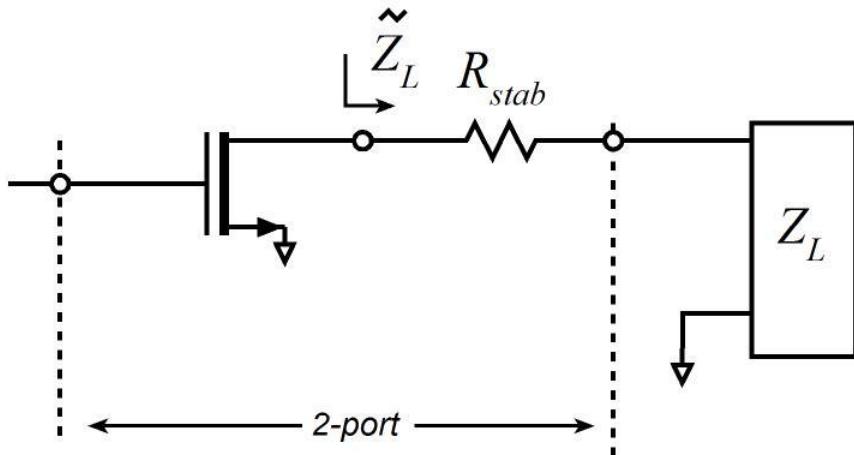
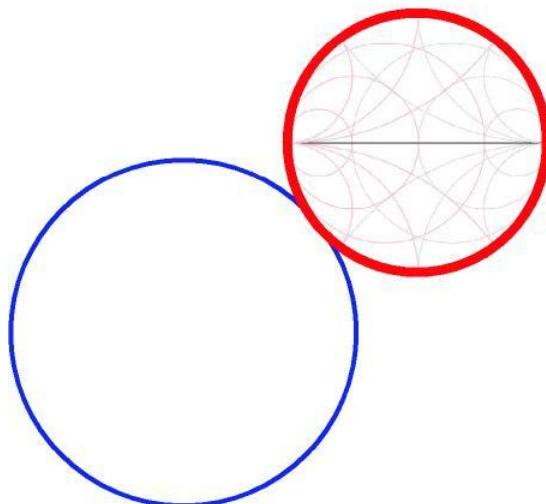
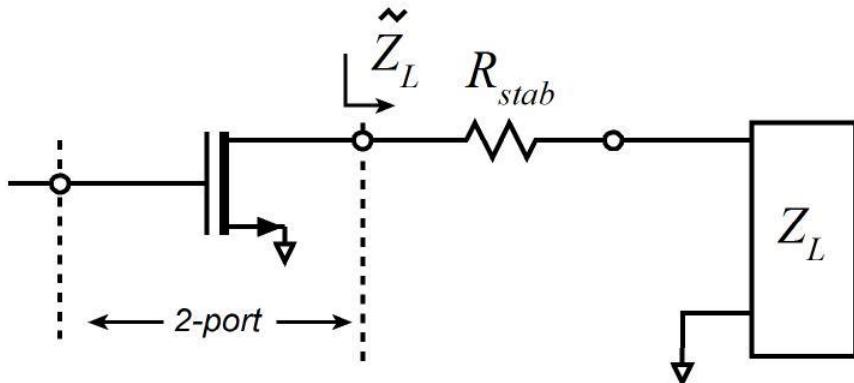
circle for
 $G = G_{stab}$



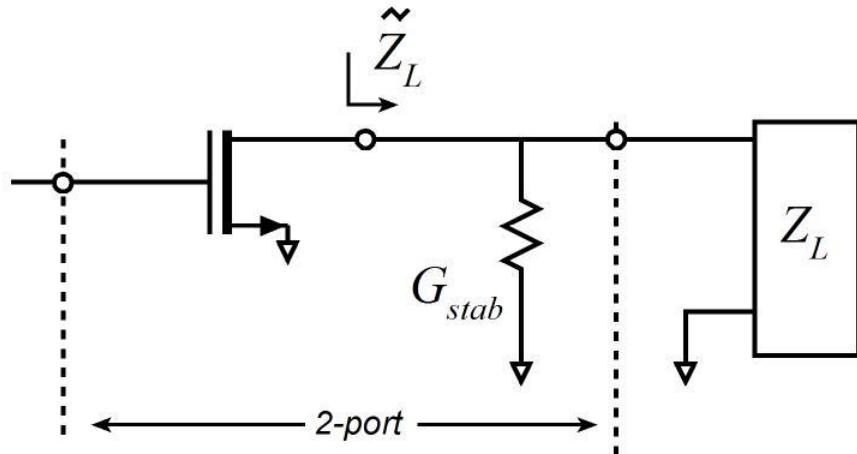
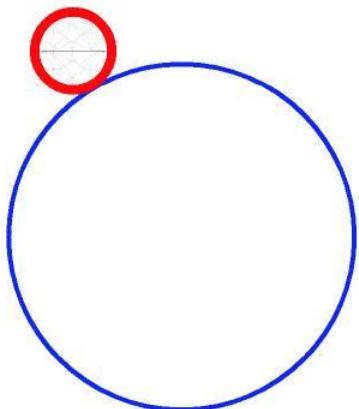
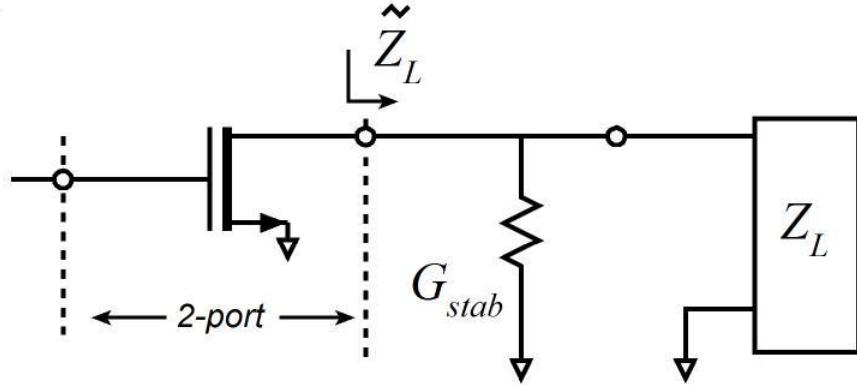
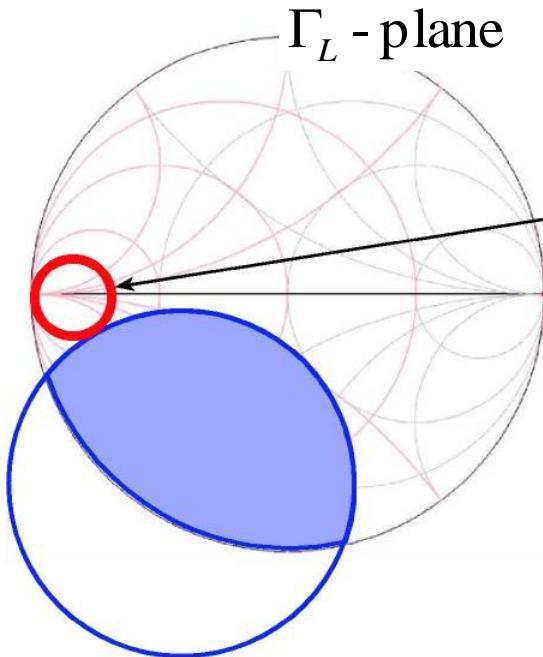
Series Stabilization On Output



*circle for
 $R=R_{stab}$*

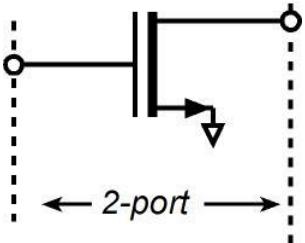


Shunt Stabilization On Output



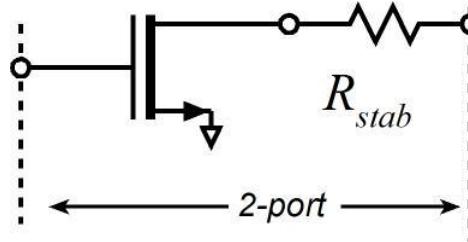
What Gain Do We Get After Stabilization ?

Before stabilization



* original * S - parameters : S_{ij}

After stabilization



* changed * S - parameters : \tilde{S}_{ij}

$$G_{\max} = \left\| \frac{S_{21}}{S_{12}} \right\| \cdot \left(K - \sqrt{K^2 - 1} \right)$$

= undefined (unstable)

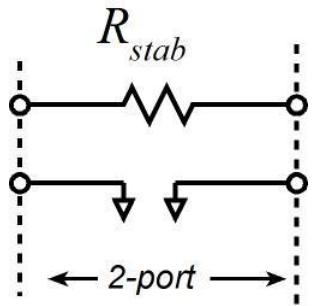
$$G_{\max \text{ stable}} = \left\| \frac{\tilde{S}_{21}}{\tilde{S}_{12}} \right\| \cdot \left(\tilde{K} - \sqrt{\tilde{K}^2 - 1} \right)$$

but $\tilde{K} = 1$ (just stable)

$$G_{\max \text{ stable}} = \left\| \frac{\tilde{S}_{21}}{\tilde{S}_{12}} \right\|$$

How do \tilde{S}_{21} and \tilde{S}_{12} compare to S_{21} and S_{12} ?

Consider First The Stabilization Network

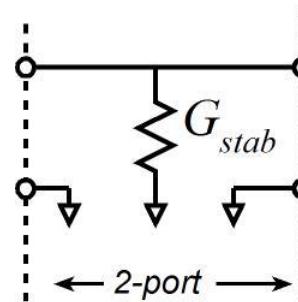


*stabilizer *S - parameters : S_{ij}^R

$$\begin{bmatrix} S_{ij}^R \end{bmatrix} = \begin{bmatrix} S_{11}^R & S_{12}^R \\ S_{21}^R & S_{22}^R \end{bmatrix}$$

$$S_{11}^R = S_{22}^R = \frac{(R_{stab} + Z_0) - Z_0}{(R_{stab} + Z_0) + Z_0}$$

$$S_{21}^R = S_{12}^R = \frac{2Z_0}{R_{stab} + 2Z_0}$$



*stabilizer *S - parameters : S_{ij}^G

$$\begin{bmatrix} S_{ij}^G \end{bmatrix} = \begin{bmatrix} S_{11}^G & S_{12}^G \\ S_{21}^G & S_{22}^G \end{bmatrix}$$

$$S_{11}^G = S_{22}^G = \frac{(G_{stab} + Y_0) - Y_0}{(G_{stab} + Y_0) + Y_0}$$

$$S_{21}^G = S_{12}^G = \frac{2Y_0}{G_{stab} + 2Y_0}$$

Key point is reciprocity : $S_{12}^R = S_{21}^R$ and $S_{12}^G = S_{21}^G$

What Gain Do We Get After Stabilization ?

S_{ij}^T : transistor S - parameters

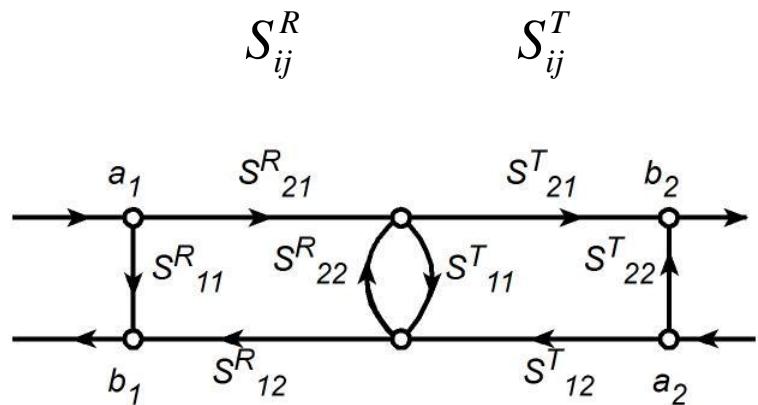
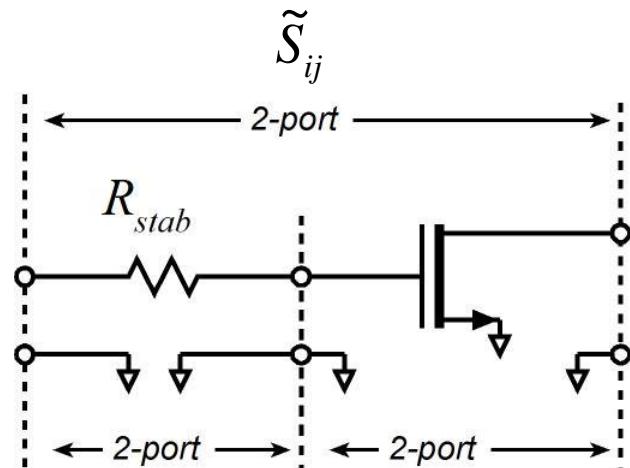
S_{ij}^R : stabilizer S - parameters

\tilde{S}_{ij} : stabilized transistor S - parameters

by inspection (Mason's gain rules) :

$$\tilde{S}_{21} = \frac{b_2}{a_1} = \frac{S_{21}^R S_{21}^T}{1 - S_{22}^R S_{11}^T} \quad \tilde{S}_{12} = \frac{b_1}{a_2} = \frac{S_{12}^R S_{12}^T}{1 - S_{22}^R S_{11}^T}$$

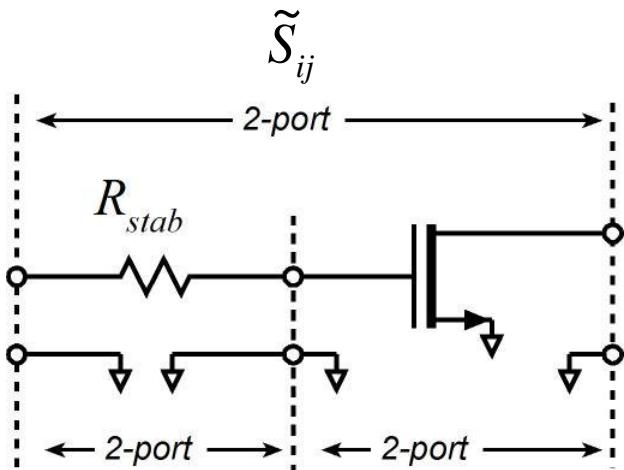
$$\frac{\tilde{S}_{21}}{\tilde{S}_{12}} = \frac{S_{21}^R}{S_{12}^R} \cdot \frac{S_{21}^T}{S_{12}^T} = \frac{S_{21}^T}{S_{12}^T} !!!$$



Consider More Carefully

Any 2 cascaded blocks follow this relationship :

$$\frac{\tilde{S}_{21}}{\tilde{S}_{12}} = \frac{S_{21}^R}{S_{12}^R} \cdot \frac{S_{21}^T}{S_{12}^T}$$



$$S_{ij}^R \quad S_{ij}^T$$

Passive reciprocal networks follow this relationship :

$$\frac{S_{21}^R}{S_{12}^R} = 1$$

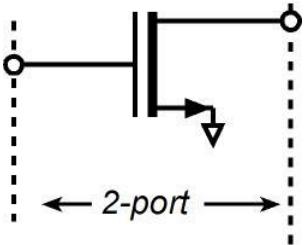
We therefore find :

$$\frac{\tilde{S}_{21}}{\tilde{S}_{12}} = \frac{S_{21}^T}{S_{12}^T}$$

Stabilizing does not change the ratio of S_{21} to S_{12} .

What Gain Do We Get After Stabilization ?

Before stabilization

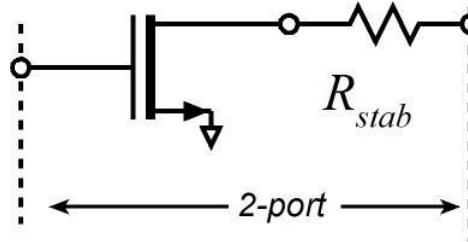


* original * S - parameters : S_{ij}

$$G_{\max} = \left\| \frac{S_{21}}{S_{12}} \right\| \cdot \left(K - \sqrt{K^2 - 1} \right)$$

= undefined (unstable)

After stabilization



* changed * S - parameters : \tilde{S}_{ij}

$$G_{\max} = \left\| \frac{\tilde{S}_{21}}{\tilde{S}_{12}} \right\| \cdot \left(\tilde{K} - \sqrt{\tilde{K}^2 - 1} \right)$$

but $\tilde{K} = 1$ (just stable)

and $\tilde{S}_{21} / \tilde{S}_{12} = S_{21} / S_{12}$

$$G_{\max_stable} = \left\| \frac{S_{21}}{S_{12}} \right\|$$

Maximum stable gain = $G_{\max_stable} = \|S_{21}\| / \|S_{12}\|$

What Does Maximum Stable Gain Mean ???

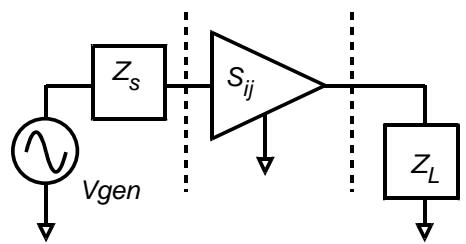
The term :"Maximum stable gain" is too short to be precise.

Maximum stable gain is the maximum gain we can obtain

*if * we also guarantee that changing Z_s and Z_L
will not make the amplifier oscillate.

Design Tools: Power Gain Definitions

Transducer Gain



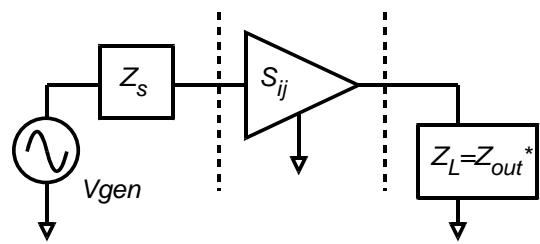
$$G_T = \frac{P_{load}}{P_{av,gen}}$$

load power

$$= \frac{\text{power available from generator}}{\text{power delivered to } Z_o \text{ load}}$$

$$= \text{general - case gain}$$

Available Gain



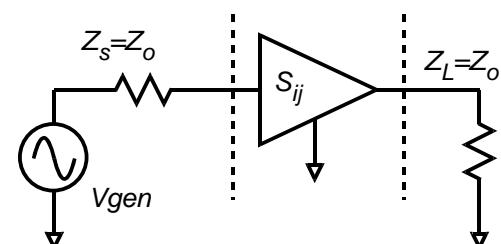
$$G_A = \frac{P_{av,a}}{P_{av,gen}}$$

power available from amplifier

$$= \frac{\text{power available from generator}}{\text{power available from generator}}$$

$$= \text{gain with output matched}$$

Insertion Gain



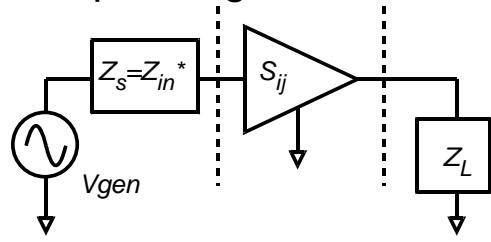
$$\|S_{21}\|^2 = \frac{P_{av,a}}{P_{av,gen}}$$

power delivered to Z_o load

$$= \frac{\text{power available from } Z_o \text{ generator}}{\text{power available from } Z_o \text{ generator}}$$

$$= \text{gain in a 50 Ohm environment}$$

Operating Gain



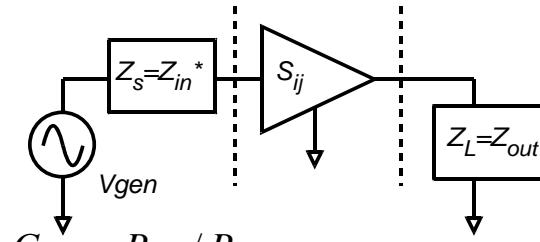
$$G_P = \frac{P_{load}}{P_{gen,delivered}}$$

load power

$$= \frac{\text{power delivered from generator}}{\text{power delivered from generator}}$$

$$= \text{gain with input matched}$$

Maximum Available Gain



$$G_{Max} = \frac{P_{av,a}}{P_{gen,delivered}}$$

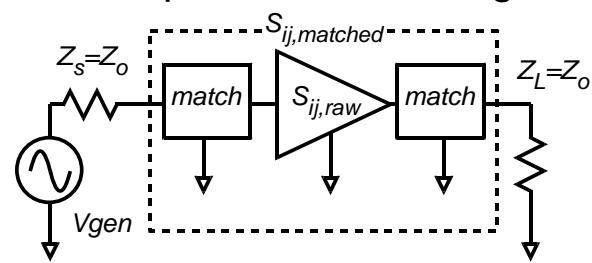
power available from amplifier

$$= \frac{\text{power delivered from generator}}{\text{power delivered from generator}}$$

$$= \text{gain with both ports matched}$$

...MAG may not exist...

After impedance-matching:



$$\|S_{21,matched}\|^2 = G_{max,raw}$$

$$S_{11,matched} = S_{22,matched} = 0$$

....but only if unconditionally stable...

Unilateral Power Gain

1) Cancel device feedback with external lossless feedback

$$\rightarrow Y_{12} = S_{12} = 0$$

2) Match input and output

Resulting power gain is Mason's Unilateral Gain

$$U = \frac{|Y_{21} - Y_{12}|^2}{4(G_{11}G_{22} - G_{21}G_{12})}$$

Monolithic amplifiers are not easily made unilateral

→ U mostly of historical relevance to IC design

For simple BJT model, U rolls off at -20 dB/decade

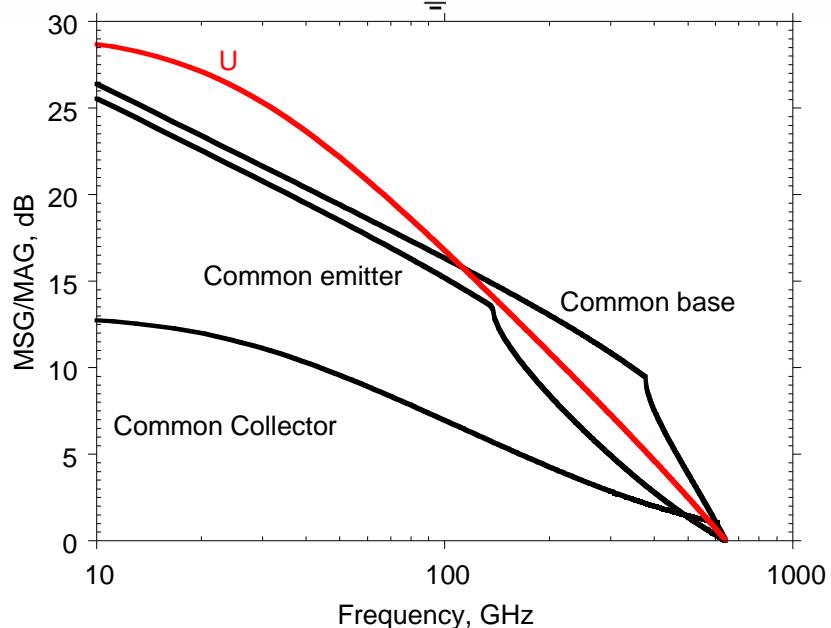
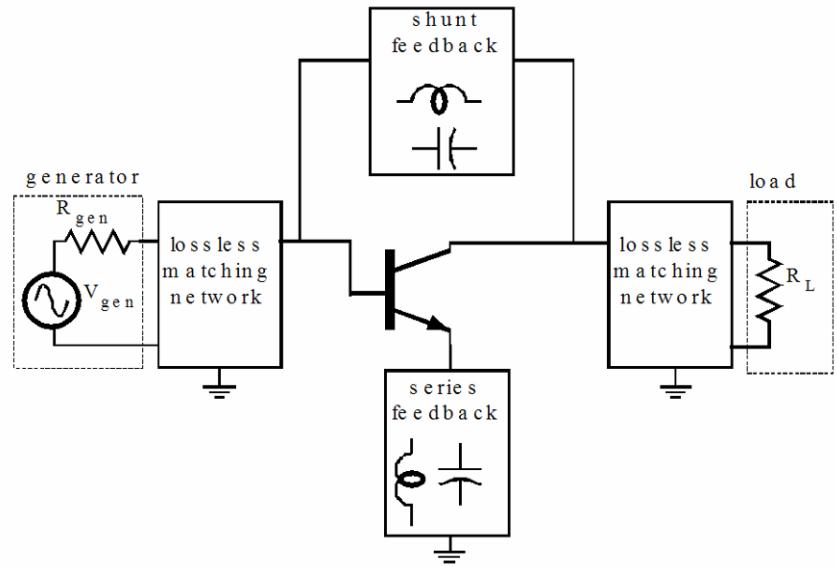
→ U useful for extrapolation to find f_{\max}

In III - V FETs, U shows peak from C_{ds} - R_s - R_d interaction

→ U hard to use for f_{\max} extrapolation

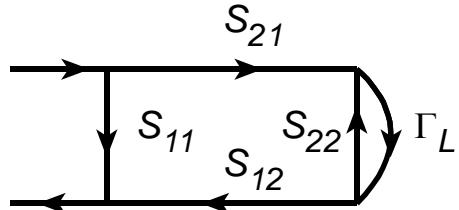
For bulk CMOS, C_{ds} is shielded by substrate

→ U should be OK for f_{\max} extrapolation



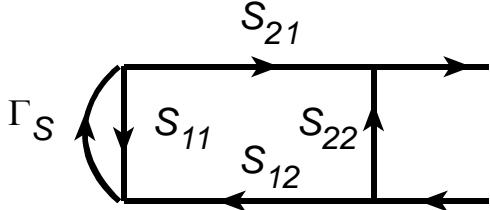
Design Tools: Stability Factors, Stability Circles

$$\Gamma_{in} = S_{11} + \Gamma_L \frac{S_{12}S_{21}}{1 - S_{22}\Gamma_L}$$

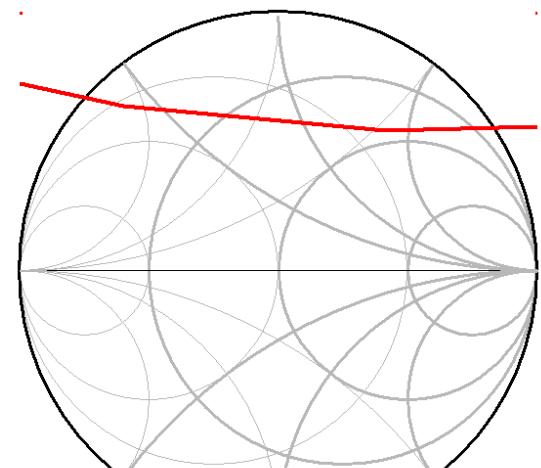


Load Stability Circle

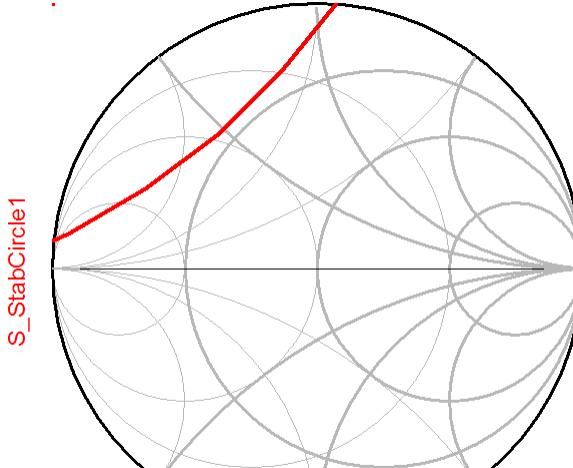
$$\Gamma_{out} = S_{22} + \Gamma_S \frac{S_{12}S_{21}}{1 - S_{11}\Gamma_S}$$



Source Stability Circle



Values of Γ_L which make
 $\|\Gamma_{in}\| = 1 \rightarrow$ beyond lies negative R_{in}



Values of Γ_S which make
 $\|\Gamma_{out}\| = 1 \rightarrow$ beyond lies negative R_{out}

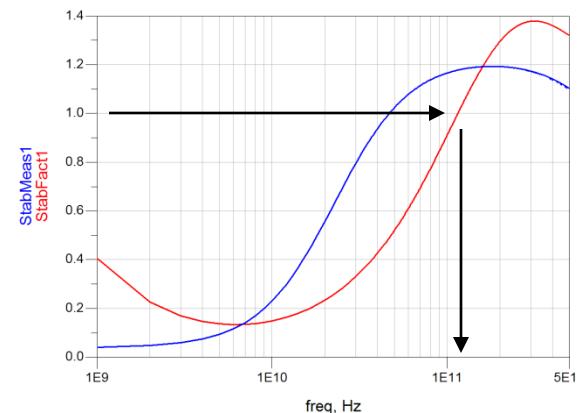
Unconditionally stable

(stable with all (Γ_L, Γ_S) if : $K =$ Rollet stability factor

$$= \frac{1 - |S_{11}|^2 - |S_{22}|^2 + \det^2[S]}{2|S_{21}S_{12}|} > 1$$

and $B =$ stability measure

$$= 1 - |S_{11}|^2 - |S_{22}|^2 - \det^2[S] > 0$$

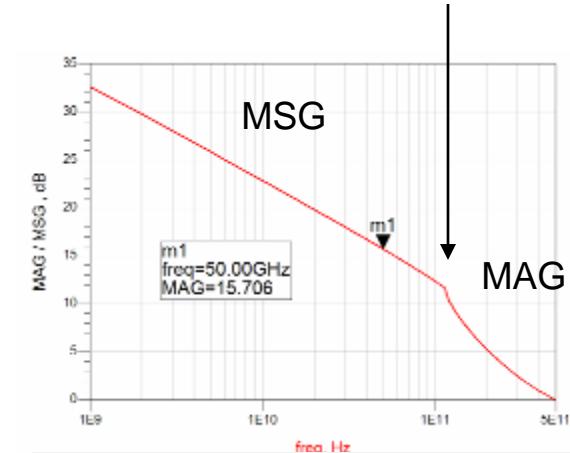
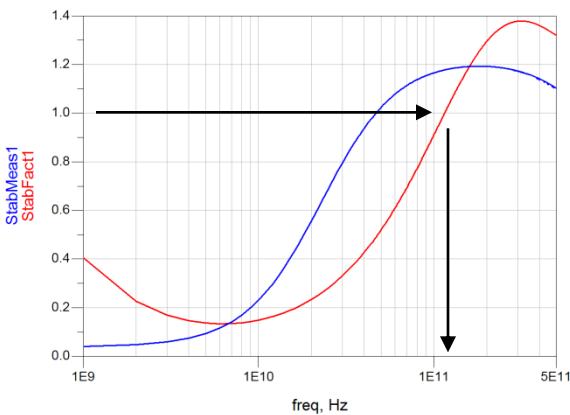


Negative port impedance → negative- R oscillator
Tuning for highest gain → infinite gain (oscillation)

Design Tools: Maximum Stable Gain

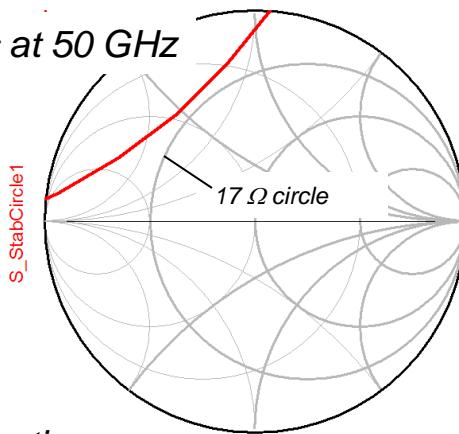
Maximum stable gain = MSG

$$= \frac{|S_{21}|}{|S_{12}|} = \frac{|Y_{21}|}{|Y_{12}|} = \frac{|Z_{21}|}{|Z_{12}|}$$

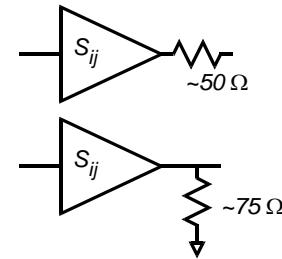
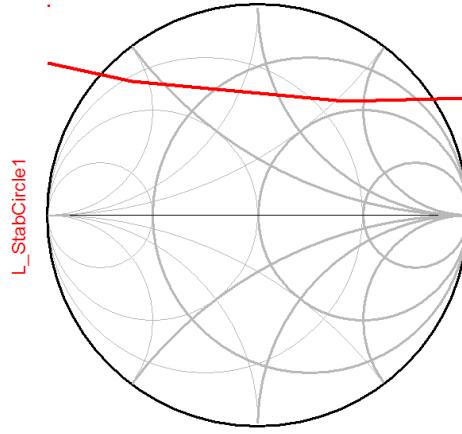
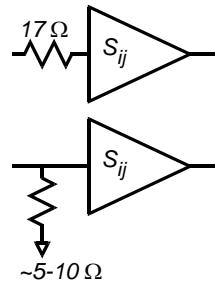


Adding series/shunt resistance excludes source or load from unstable regions → stabilizes

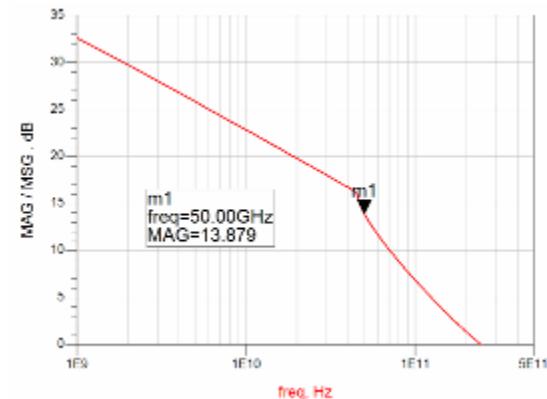
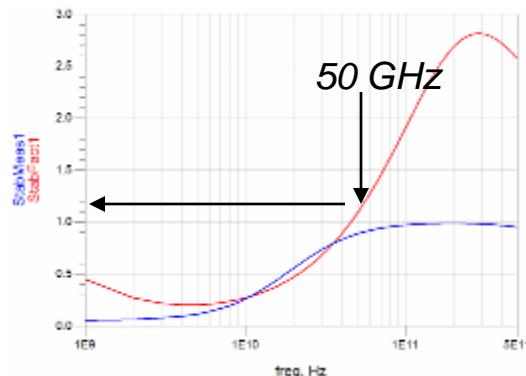
circles at 50 GHz



stabilization methods



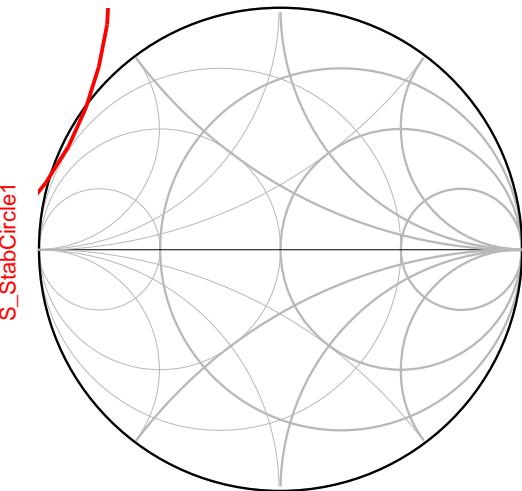
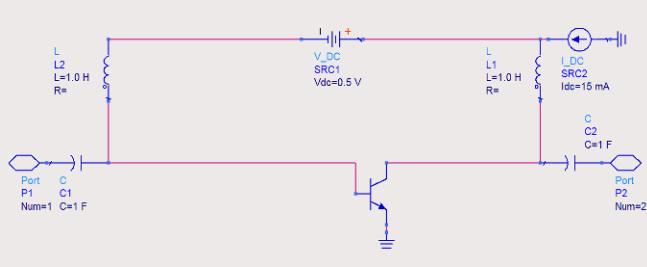
results



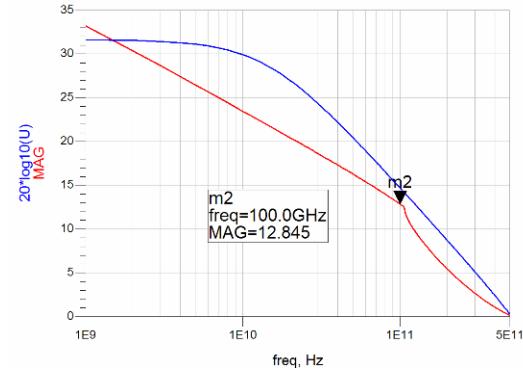
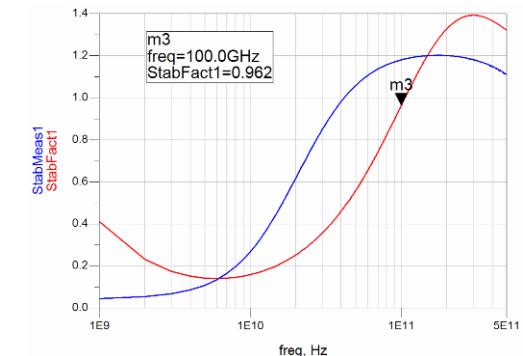
Design Procedure: Simple Gain-Matched Amplifier

First:
stabilize at the design frequency

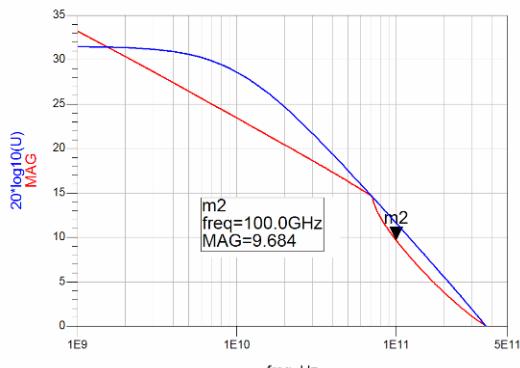
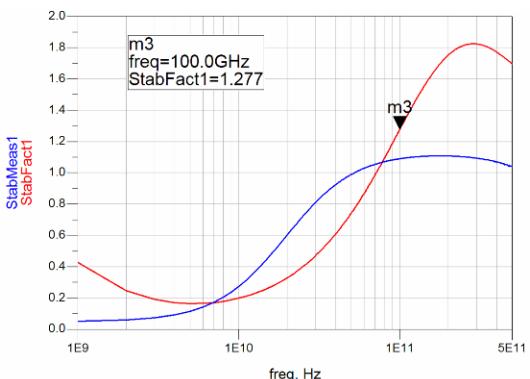
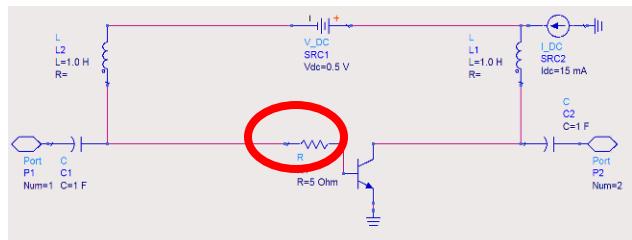
---device is potentially unstable
at 100 GHz design frequency



source stability circle:
~5 Ohm on input will
overstabilize the device



After stabilizing
(slightly over-stabilizing)



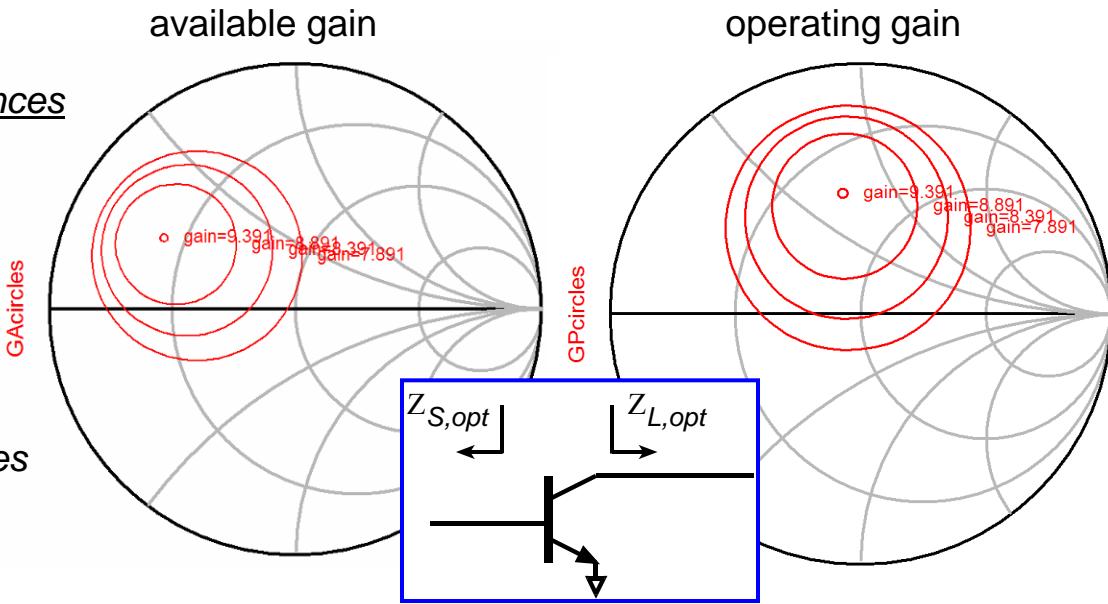
Design Procedure: Simple Gain-Matched Amplifier

Second:

Determine required interface impedances

The G_a & G_p circles define the source & load impedances which the transistor must see

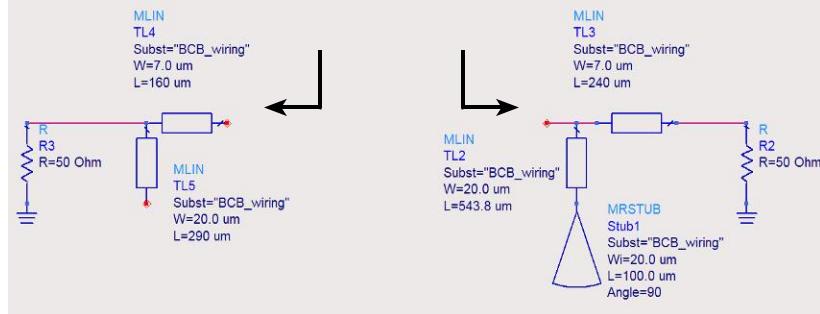
...it is necessary to OVERSTABILIZE the device to move the G_a & G_p circles towards the Smith chart center



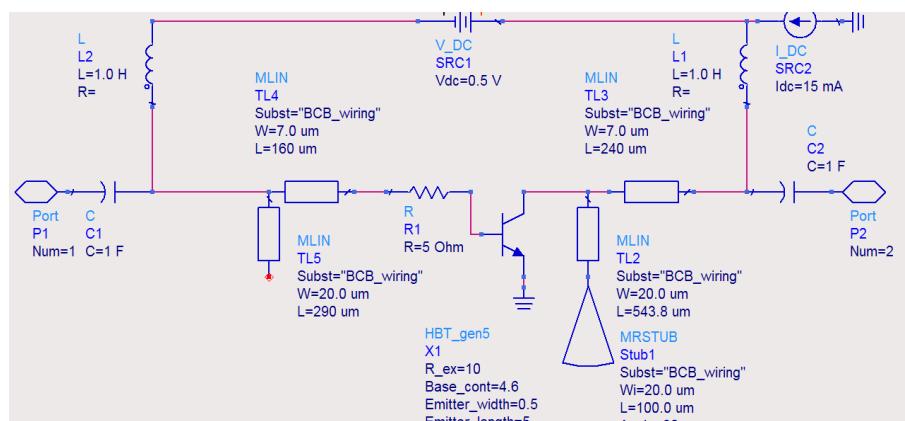
Third:

Design Input & Output Tuning Networks

...to provide these impedances...

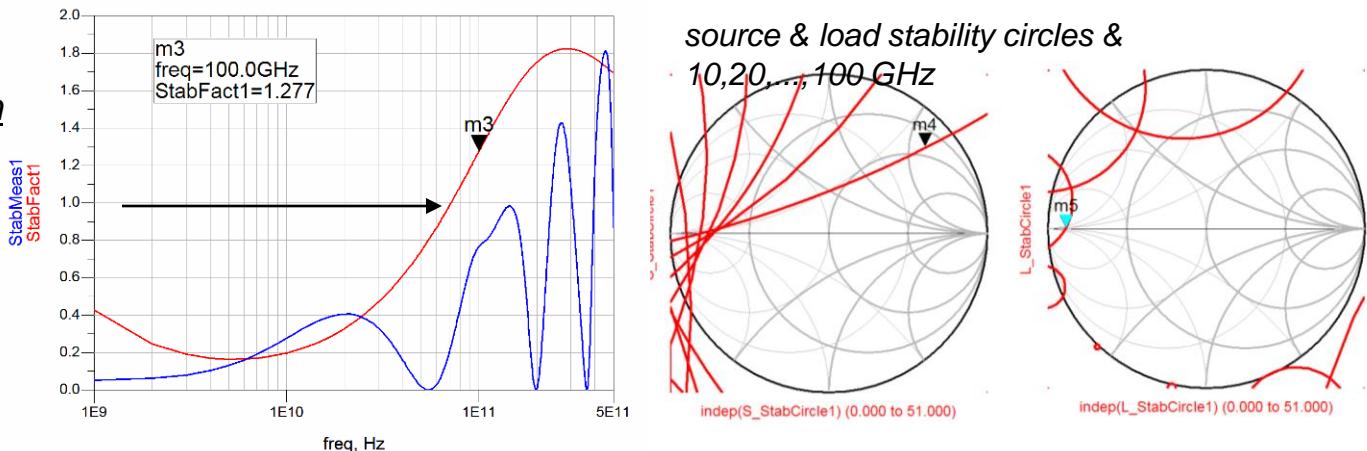


...added to device, the amplifier is not yet complete...

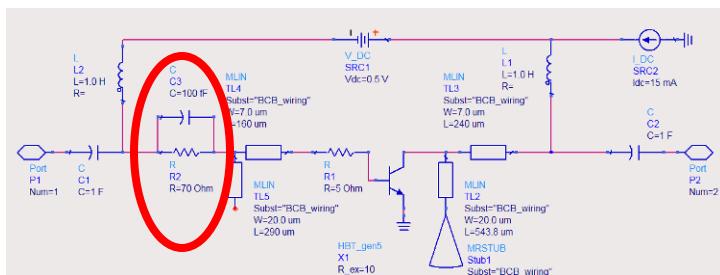


Design Procedure: Simple Gain-Matched Amplifier

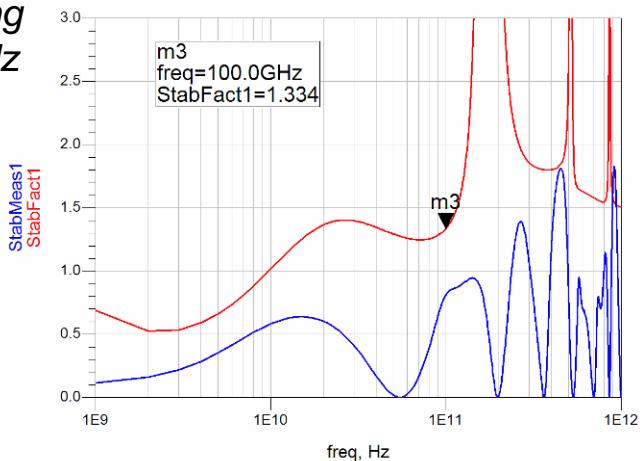
Forth:
Add out-of-band stabilization
potentially unstable
below 75 GHz



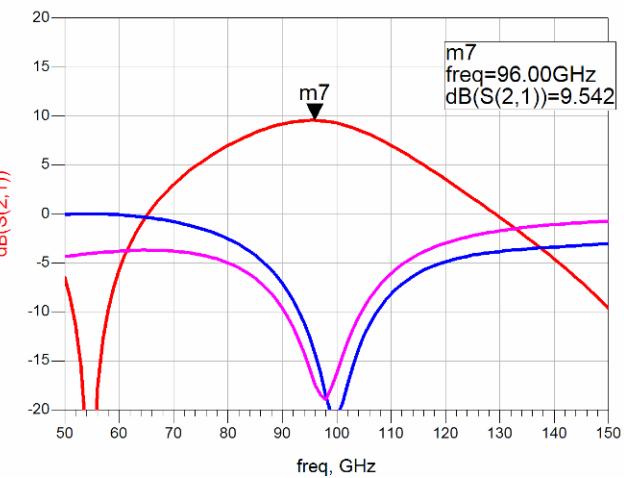
with frequency-selective series stabilization



...caused only slight mistuning
& slight gain drop @ 100 GHz



...and is unconditionally stable above 10 GHz



Design Procedure: Effect of Line Losses

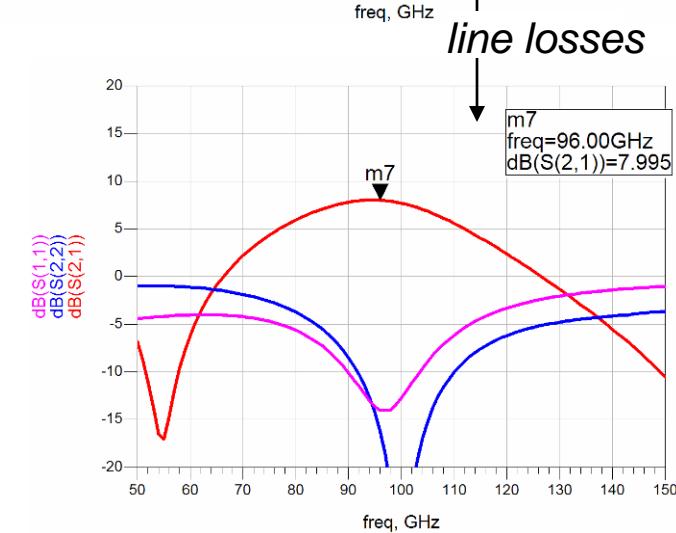
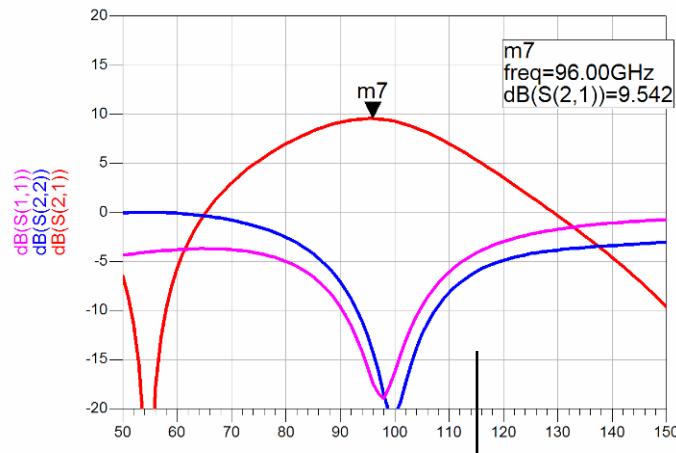
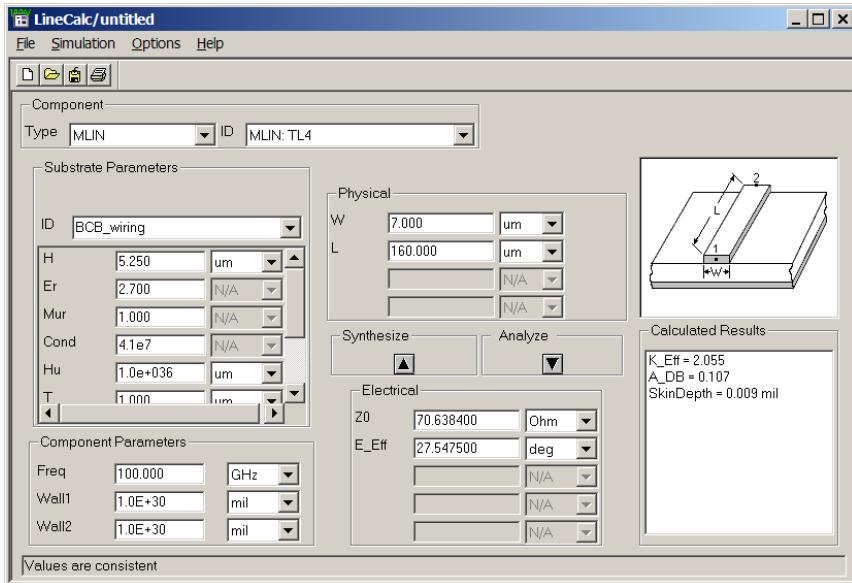
Finally:
adjusting for line losses

high line skin effect losses → reduced gain

but line losses also increase stability factor

loss in gain are partly recovered
by reducing stabilization resistance &
re-tuning the design

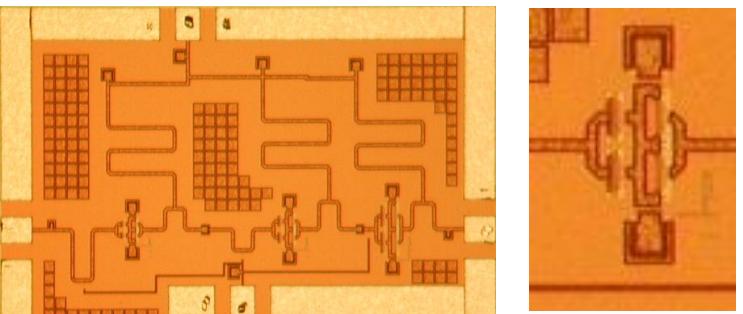
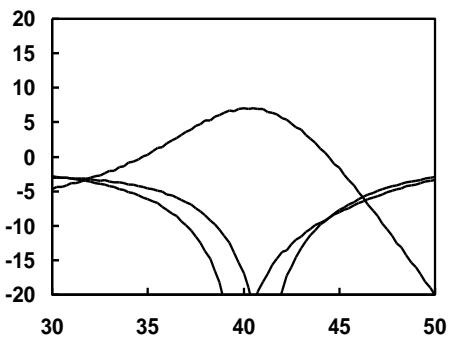
--no analytical procedure; just component tweaking



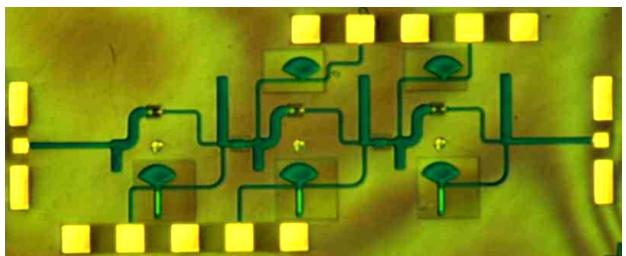
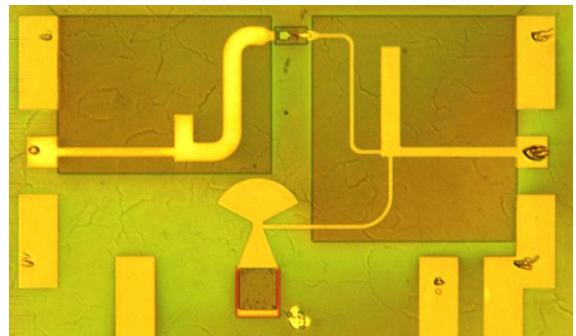
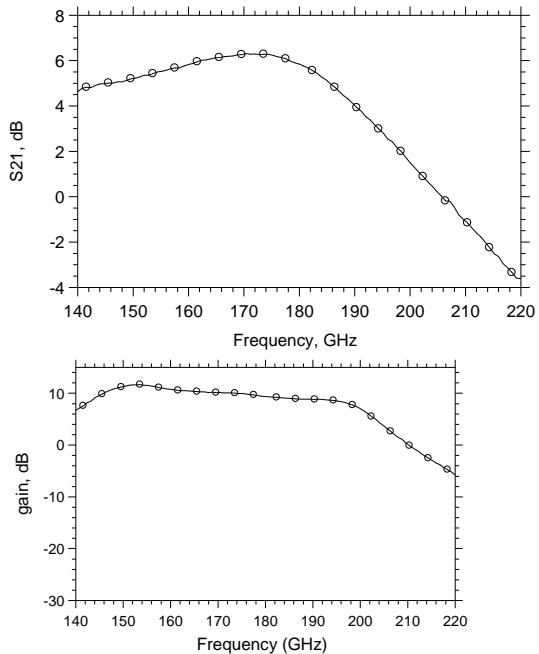
line losses have severe impact
...in VLSI wiring environment
...particularly at 50 + GHz
...particularly with high-power amplifiers

Tuned Amplifier Examples

3-stage cascode in 180 nm CMOS



III-V HBT small-signal amplifiers



Note: simple gain-tuned amplifiers → limited applications

Transmitters need power amplifiers: need output loadline-match, not gain-match

Receivers need low-noise amplifiers: need input noise-match, not gain-match